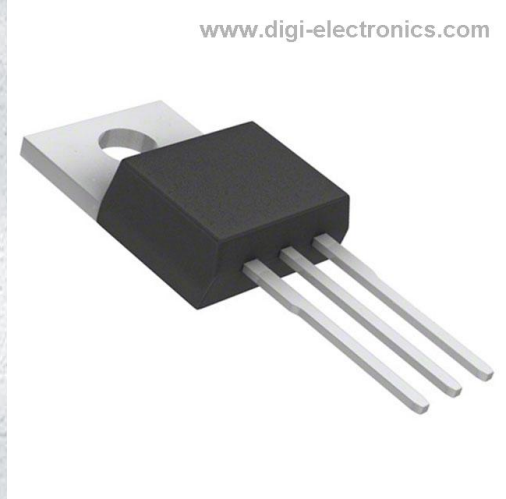
KSA940H1TU Datasheet



https://www.DiGi-Electronics.com

DiGi Electronics Part Number	KSA940H1TU-DG
Manufacturer	onsemi
Manufacturer Product Number	KSA940H1TU
Description	TRANS PNP 150V 1.5A TO220-3
Detailed Description	Bipolar (BJT) Transistor PNP 150 V 1.5 A 4MHz 1.5 W Through Hole TO-220-3

Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
KSA940H1TU	onsemi
Series:	Product Status:
-	Obsolete
Transistor Type:	Current - Collector (Ic) (Max):
PNP	1.5 A
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ Ib, Ic:
150 V	1.5V @ 50mA, 500mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
10µA (ICBO)	40 @ 500mA, 10V
Power - Max:	Frequency - Transition:
1.5 W	4MHz
Operating Temperature:	Mounting Type:
150°C (TJ)	Through Hole
Package / Case:	Supplier Device Package:
TO-220-3	TO-220-3
Base Product Number:	
KSA940	

Environmental & Export classification

Moisture Sensitivity Level (MSL):	REACH Status:
1 (Unlimited)	REACH Unaffected
ECCN:	HTSUS:
EAR99	8541.29.0095

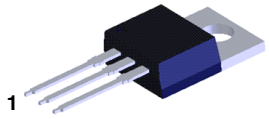
onsemi

DATA SHEET
www.onsemi.com

Vertical Deflection Output Power Amplifier

KSA940

PNP Epitaxial Silicon Transistor
Complement to KSC2073



TO−220−3LD
CASE 340AT

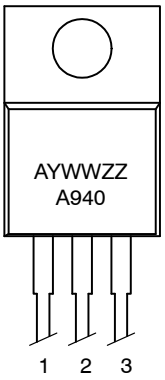
- These are Pb−Free Devices

ABSOLUTE MAXIMUM RATINGS
(T_C = 25°C unless otherwise noted.)

Symbol	Parameter	Value	Unit
V_{CBO}	Collector−Base Voltage	−150	V
V_{CEO}	Collector−Emitter Voltage	−150	V
V_{EBO}	Emitter−Base Voltage	−5	V
I_C	Collector Current	−1.5	A
I_B	Base Current	−0.5	A
P_C	Collector Dissipation (T_a=25°C)	1.5	W
P_C	Collector Dissipation (T_C=25°C)	25	W
T_J	Junction Temperature	150	°C
T_{STG}	Storage Temperature	−55 ~ 150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

MARKING DIAGRAM



1: Base
2: Collector
3: Emitter

A = Assembly Plant Code
YWW = 3−Digit Date Code (Year and Week)
ZZ = 2−Digits Lot Run Traceability Code
A940 = Specific Device Code

ELECTRICAL CHARACTERISTICS
(T_C = 25°C unless otherwise noted.)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
I_{CBO}	Collector Cut−off Current	V_{CB} = − 120 V, I_E = 0	−	−	−10	μA
I_{EBO}	Emitter Cut−off Current	V_{EB} = − 5 V, I_C = 0	−	−	−10	μA
h_{FE}	DC Current Gain	V_{CE} = − 10V, I_C = − 500 mA	40	75	140	
V_{CE}(sat)	Collector−Emitter Saturation Voltage	I_C = − 500 mA, I_B = − 50 mA	−	−	−1.5	V
V_{BE}(on)	Base−Emitter ON Voltage	V_{CE} = − 10 V, I_C = − 500 mA	−0.65	−0.75	−0.85	V
f_T	Current Gain Bandwidth Product	V_{CE} = − 10 V, I_C = − 500 mA	−	4	−	MHz
C_{ob}	Output Capacitance	V_{CB} = − 10 V, I_E = 0, f = 1 mHz	−	55	−	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

ORDERING INFORMATION

Device	Package	Shipping
KSA940TU	TO−220−3LD (Pb−Free)	1000 Units / Tube

KSA940

TYPICAL PERFORMANCE CHARACTERISTICS

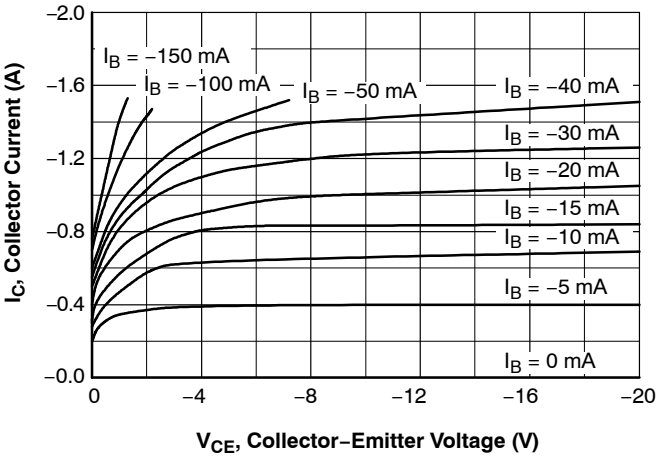


Figure 1. Static Characteristic

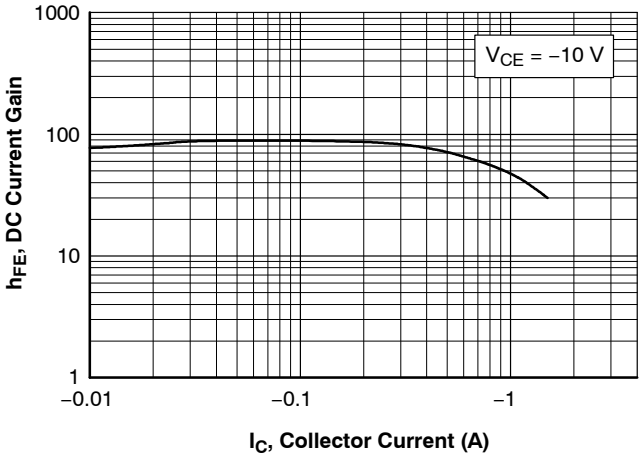


Figure 2. DC Current Gain

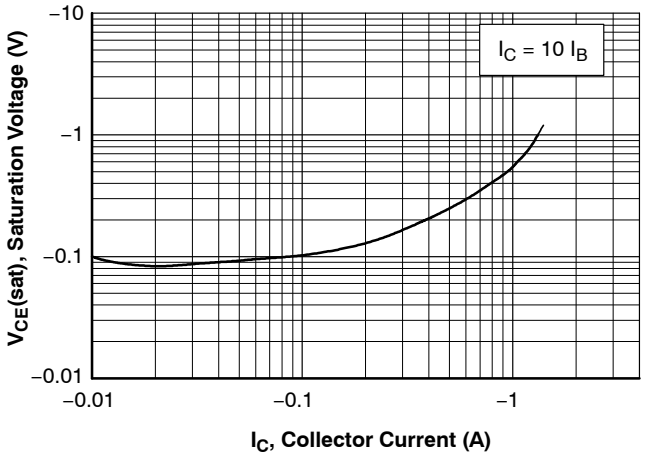


Figure 3. Collector−Emitter Saturation Voltage

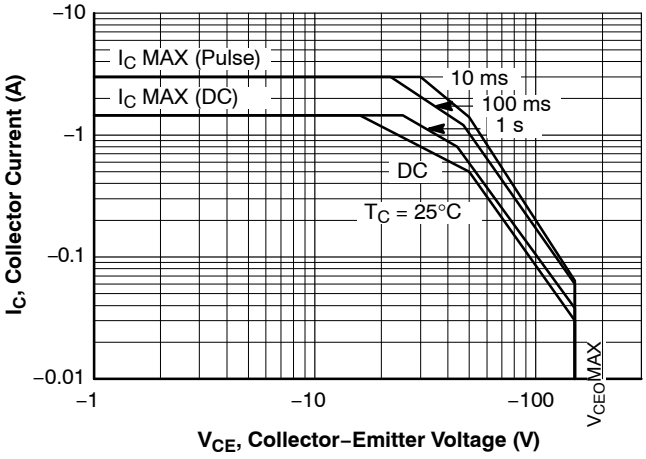


Figure 4. Safe Operating Area

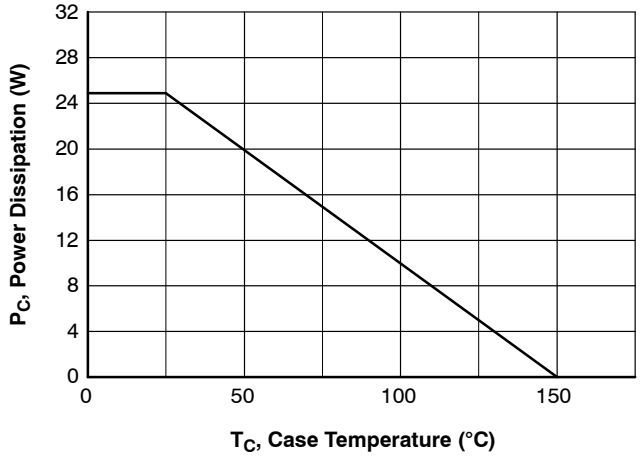
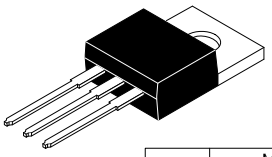


Figure 5. Power Derating

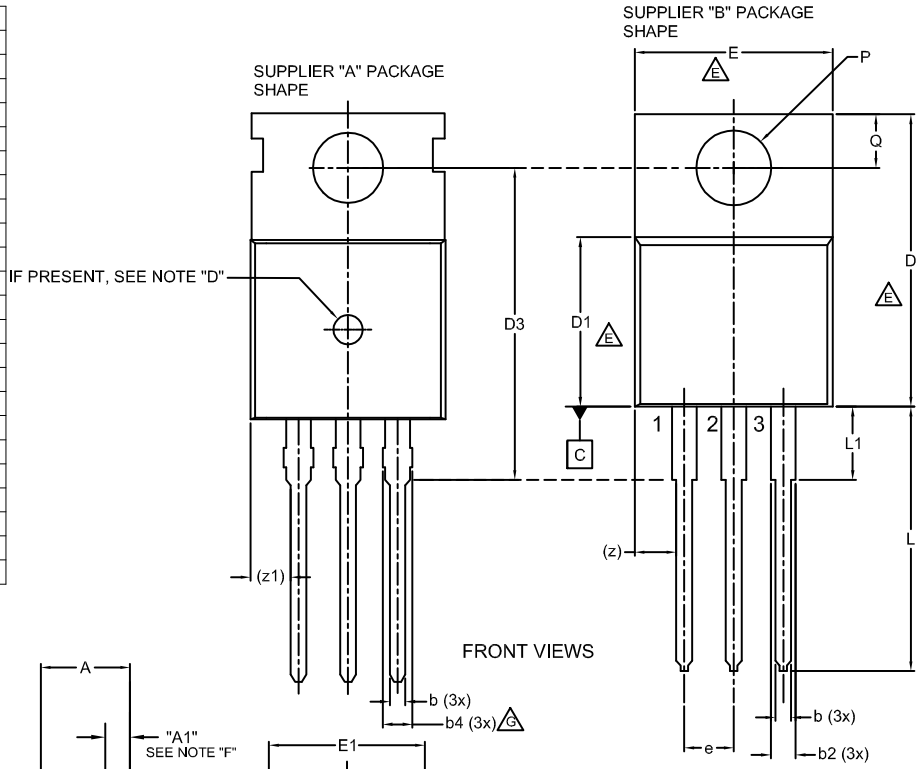
MECHANICAL CASE OUTLINE
PACKAGE DIMENSIONS

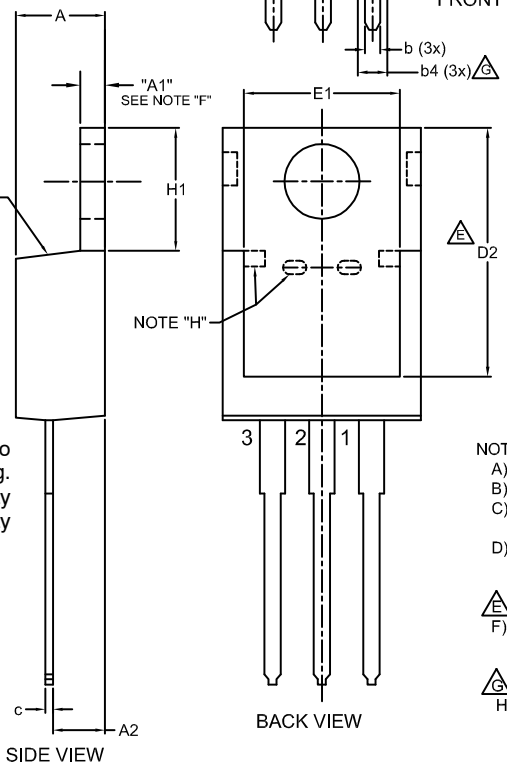


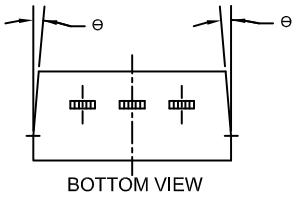
TO−220−3LD
CASE 340AT
ISSUE B

DATE 08 AUG 2022

DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
A	4.00	--	4.70
A1	SEE NOTE "F"		
A2	2.10	--	2.85
b	0.55	--	1.00
b2	1.10	--	1.62
b4	1.42	--	1.62
c	0.36	--	0.60
D	13.90	--	16.30
D1	8.13	--	9.40
D2	11.50	--	14.30
D3	15.42	--	16.51
E	9.65	--	10.67
E1	7.59	--	8.65
e	2.40	--	2.67
H1	6.06	--	6.69
L	12.70	--	14.04
L1	2.70	--	4.10
P	3.50	--	4.00
Q	2.50	--	3.40
z	2.13 REF		
z1	2.06 REF		
Θ	3°	–	5°







GENERIC MARKING DIAGRAM*

XXXX = Specific Device Code
A = Assembly Location
Y = Year
WW = Work Week
ZZ = Assembly Lot Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “▪”, may or may not be present. Some products may not follow the Generic Marking.

NOTES:
A) REFERENCE JEDEC, TO-220, VARIATION AB
B) ALL DIMENSIONS ARE IN MILLIMETERS.
C) DIMENSIONS COMMON TO ALL PACKAGE SUPPLIERS EXCEPT WHERE NOTED [ ].
D) LOCATION OF MOLDED FEATURE MAY VARY (LOWER LEFT CORNER, LOWER CENTER AND CENTER OF THE PACKAGE)
E DOES NOT COMPLY JEDEC STANDARD VALUE.
F) "A1" DIMENSIONS AS BELOW:
SINGLE GAUGE = 0.51 - 0.61
DUAL GAUGE = 1.10 - 1.45
G PRESENCE IS SUPPLIER DEPENDENT
H) SUPPLIER DEPENDENT MOLD LOCKING HOLES IN HEATSINK.

DOCUMENT NUMBER:	**98AON13818G**	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped “CONTROLLED COPY” in red.	
DESCRIPTION:	**TO−220−3LD**		**PAGE 1 OF 1**

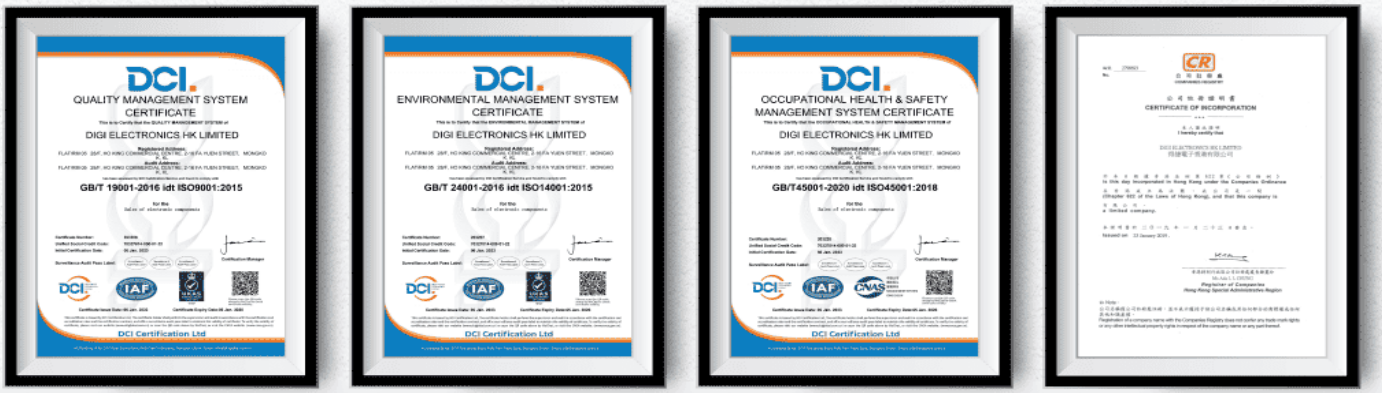
ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:
Technical Library: www.onsemi.com/design/resources/technical−documentation
onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support
For additional information, please contact your local Sales Representative at www.onsemi.com/support/sales

OUR CERTIFICATE

DiGi provide top-quality products and perfect service for customer worldwide through standardization, technological innovation and continuous improvement. DiGi through third-party certification, we striciy control the quality of products and services. Welcome your RFQ to Email: Info@DiGi-Electronics.com



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.